
 AC105
Ge - PNP

 $-U_{ce}/U_{cb}$
18 / 40V

 $-I_c$
1A

 N
400mW

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C900

SI NPN transistor


 B C E
bottom view
von unten

 U_{ce}/U_{cb} : 25/30V

 I_c : 20mA

 $\beta (I_c/I_b)$: -

N: 250mW

F: 100MHz

 T_{max} : -

 the C900 is a silicon NPN transistor, $U_{ce} = 25V$, $I_c = 20mA$,
applications: general purpose, low noise

Source: 2SC900

Picture: -

 advanced information for C900
(toggle)

 OEM: Nippon Electric Comp. Ltd. NEC,
Japan

Package: TO-92

datasheet (jpg): -

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2SC2674, 2SC2675

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C900

SI NPN transistor


 bottom view
von unten

 U_{ce}/U_{cb} : 25/30V

 I_c : 50mA

 $\beta (I_c/I_b)$: 0.12-1k

N: 250mW

F: 100MHz

 T_{max} : 150°C

 the C900 is a silicon NPN transistor preferred for use in low
frequency, low noise amplifier applications

Source: KSC900

Picture: -

advanced information for C900

OEM: Samsung Electronics CO. LTD.

Package: TO-92

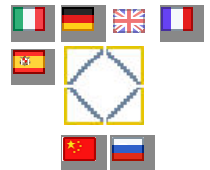
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